AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Martin E. K rdesch, et al.							Docket No. 90065.001020 (XDEV1100)			
Serial No. 09/682,151	1	g Date 27, 2001		Examiner Chris Chu			Group Art Unit 2815			
Invention: CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR										
DEVICES FORMED BY THOSE METHODS										
TO THE COMMISSIONER FOR PATENTS:										
Fransmitted he with is an amendment in the above-identified application.										
The fee has been calculated and is transmitted as shown below.										
	CLAIMS AS AMENDED									
	CLAIMS REMAINING	HIGHEST #		NUMBER EXTRA	F	RATE	ADDITIONAL			
-	AFTER AMENDMENT	PREV. PAID FOR		CLAIMS PRESENT			FEE			
TOTAL CLAIMS	15 -	20 =		0	x	\$18.	<u> </u>			
INDEP. CLAIMS	2 -	3 =		0	x	\$86.				
Multiple Depender	nt Claims (check if appli	licable)					\$0.00			
		TOTAL ADDITIO	NAL I	FEE FOR THIS AME	ENDN	MENT	\$0.00			
No additional fee is required for amendment. Please charge Deposit Account No. in the amount of A check in the amount of to cover the filing fee is enclosed. The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. Any additional filing fees required under 37 C.F.R. 1.16. Any patent application processing fees under 37 CFR 1.17.										
Dated: 14-JAN-2004										
Laurence S. Roack Reg. No. 45,044 Law Firm of Thor 16 E. Main Street, Rochester, New Y	ch, Esq. mas R. FitzGerald , Suite 210			on January 14,	2004		ent and fee is being deposited with the U.S. Postal Service as F.R. 1.8 and is addressed to the			

onJanuary 14, 2004 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450

Signature of Person Mailing Correspondence

Penny P. Clements

Typed or Printed Name of Person Mailing Correspondence

									
CERTIFICATE OF N Applicant(s): Martin E.	900	Docket No. 065.001020/17732.8011.00							
Serial No. 09/682,151	Filing Date July 27, 2001	Examiner Chris C. Chu		Group Art Unit 2815					
Invention: CONTACT N	METHOD FOR THIN SILICON THOSE METHODS	CARBIDE EPITAXIAL LAY	ER AN	D SEMICONDUCTOR					
July 16 20 Menters	S Amandmant (total 13 pages)		-						
I hereby certify that this Amendment (total 13 pages) (Identify type of correspondence)									
is being deposited with the United States Postal Service as first class mail in an envelope addressed to:									
Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on January 14, 2004 (Date)									
	Note: Feeb paper must be		Mailing						
	Note: Each paper must na	ve its own certificate of mailing.							

PATENT Docket: 90065.001020 (XDEV1100) Reply to Office Action of 15 Oct. 2003

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

Applicant : Martin E. Kordesch, et al.

Serial No. : 09/682,151) Examiner: Chu, Chris

Filed : 27 July 2001) Art Unit: 2815

For : CONTACT METHOD FOR THIN

SILICON CARBIDE EPITAXIAL)
LAYER AND SEMICONDUCTOR)
DEVICES FORMED BY THOSE)

METHODS

AMENDMENT

Commissioner for Patents

MS: NON-FEE AMENDMENT

P.O. Box 1450

Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action mailed 15 October 2003, Applicants hereby submit the following Amendment in compliance with 37 CFR 1.121 as revised in the Final Rule: Changes to Implement Electronic Maintenance of Official Patent Application Records, 68 Fed. Reg. 38611 (June 30, 2003).